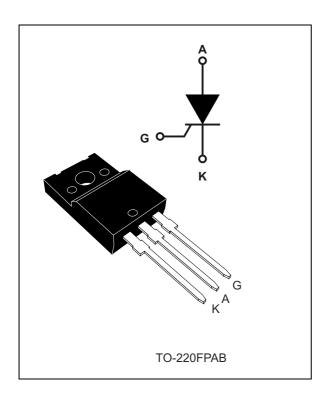
## TN1610H-6FP



#### High temperature 16 A SCRs

Datasheet - production data



#### **Features**

- High junction temperature: T<sub>i</sub> = 150 °C
- High noise immunity dV/dt = 1 kV/μs up to 150 °C
- Gate triggering current I<sub>GT</sub> = 10 mA
- Blocking voltage V<sub>DRM</sub>/V<sub>RRM</sub> = 600 V
- High turn on current rise dl/dt: 100 A/µs
- ECOPACK<sup>®</sup>2 compliant component
- Complies with UL standards (File ref: E81734)
- Insulated package TO-220FPAB:
  - Insulated voltage: 2000 VRMS

#### **Applications**

- Voltage regulator circuits for motorbikes
- · Inrush current limiting circuits
- Motor control circuits and starters
- Light dimmers
- Solid state relays

#### **Description**

Thanks to a junction temperature up to 150 °C and an insulated TO-220FPAB package, the TN1610H-6FP offers high thermal performance up to 16 A rms.

The trade-off between the device's noise immunity (dV/dt = 1 kV/ $\mu$ s) its gate triggering current (I<sub>GT</sub> = 10 mA) and its turn-on current rise (dI/dt = 100 A/ $\mu$ s) allows the design of robust and compact control circuits for voltage regulators in motorbikes and industrial drives, overvoltage crowbar protection, motor control circuits in power tools and kitchen appliances, and inrush current limiting circuits.

The insulated fullpack package allows a back-to-back configuration.

Table 1. Device summary

Order code	Package	V <sub>DRM</sub> /V <sub>RRM</sub>	I <sub>GT</sub>	
TN1610H-6FP	TO-220FPAB	600 V	10 mA	

Characteristics TN1610H-6FP

## 1 Characteristics

**Table 2. Absolute ratings** 

Symbol	Parameter	r		Value	Unit
I <sub>T(RMS)</sub>	On-state rms current (180° conduction angle)		T <sub>c</sub> = 83 °C	16	Α
			T <sub>C</sub> = 83 °C	10	
I <sub>T(AV)</sub>	Average on-state current (180° conduction angle)		T <sub>C</sub> = 102 °C	8	Α
			T <sub>C</sub> = 117 °C	6	
ı	Non repetitive surge peak on-state curre	ent	t = 8.3ms	153	۸
I <sub>TSM</sub>	(T <sub>j</sub> initial = 25 °C)		t = 10 ms	140	Α
l <sup>2</sup> t	I <sup>2</sup> t value for fusing (T <sub>j</sub> initial = 25 °C)		$t_p = 10 \text{ ms}$	98	A²s
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , $t_r \le 100 \text{ ns}$ , $T_i = 25 \text{ °C}$		f = 60 Hz	100	A/µs
V <sub>DRM</sub> , V <sub>RRM</sub>	Repetitive peak off-state voltage			600	٧
I <sub>GM</sub>	Peak gate current	t <sub>p</sub> = 20 μs	T <sub>j</sub> = 150 °C	4	Α
P <sub>G(AV)</sub>	Average gate power dissipation		T <sub>j</sub> = 150 °C	1	W
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Operating junction temperature range		- 40 to + 150 - 40 to + 150	°C	
T <sub>L</sub>	Maximum lead temperature for soldering during 10 s			260	°C
V <sub>ins</sub>	Insulation rms voltage, 1 minute	2000	٧		

Table 3. Electrical characteristics ( $T_j = 25$  °C, unless otherwise specified)

Symbol	Test conditions			Value	Unit
1.	$V_D = 12 \text{ V}, R_L = 33 \Omega$		Тур.	4.5	mA
I <sub>GT</sub>				Max.	10
V <sub>GT</sub>	$V_D = 12 \text{ V}, R_L = 33 \Omega$		Max.	1.3	V
$V_{GD}$	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$ $T_j = 150 \text{ °C}$		Min.	0.2	V
I <sub>H</sub>	$I_L$ $I_G = 1.2 \times I_{GT}$		Max.	30	mA
IL			Max.	60	mA
dV/dt			Min.	1000	V/µs
t <sub>gt</sub>	$I_T = 32 \text{ A}, V_D = 600 \text{ V}, I_G = 100 \text{ mA},$ $(dI_G/dt) \text{max} = 0.2 \text{ A/µs}$		Тур	1.9	μs
t <sub>q</sub>	$V_D = 402 \text{ V}, V_R = 25 \text{ V}, I_T = 16 \text{ A}, \\ (dI_G/dt) \text{max} = 30 \text{A/} \mu \text{s}, dV_D/dt = 40 \text{ V/} \mu \text{s}$ $T_j = 150 \text{ °C}$		Тур	70	μs

TN1610H-6FP Characteristics

**Table 4. Static characteristics** 

Symbol	Test conditions			Value	Unit
$V_{TM}$	$I_{TM} = 32 \text{ A}, t_p = 380  \mu\text{s}$	T <sub>j</sub> = 25 °C	Max.	1.6	V
V <sub>t0</sub>	Threshold voltage	T <sub>j</sub> = 150 °C	Max.	0.82	V
R <sub>d</sub>	Dynamic resistance	T <sub>j</sub> = 150 °C	Max.	25	mΩ
I <sub>DRM,</sub>	V - V - V	T <sub>j</sub> = 25 °C	- Max.	5	μA
I <sub>RRM</sub>	$V_D = V_{DRM}, V_R = V_{RRM}$	T <sub>j</sub> = 150 °C		1.5	mA

Table 5. Thermal resistance

Symbol	Parameter	Value	Unit
R <sub>th(j-c)</sub>	Junction to case (AC)	4.5	°C/W
R <sub>th(j-a)</sub>	Junction to ambient (DC)	60	°C/W

Figure 1. Maximum power dissipation versus average on-state current

P(W) 18 16 α = 180 ° DC 14 α = 120 °  $\alpha = 90$ 12 10 8 6 4 2  $I_{T(AV)}(A)$ 5 10 15

Figure 2. Average and DC on-state current versus case temperature

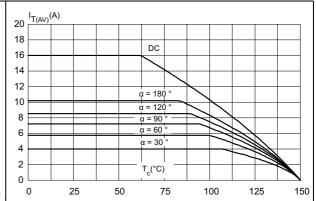
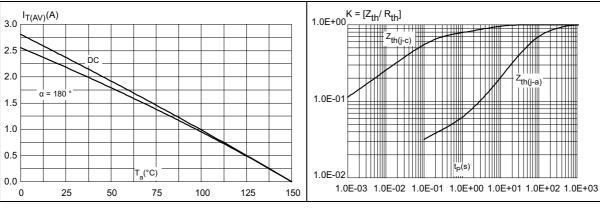


Figure 3. Average and DC on-state current versus ambient temperature

Figure 4. Relative variation of thermal impedance versus pulse duration



Characteristics TN1610H-6FP

Figure 5. Relative variation of gate triggering current and gate voltage versus junction temperature (typical values)

2.5 2.0 1.5 1.0 V<sub>GT</sub> 0.5 0.0 -50 -25 0 25 50 75 100 125 150

Figure 6. Relative variation of holding current and latching current versus junction temperature (typical values)

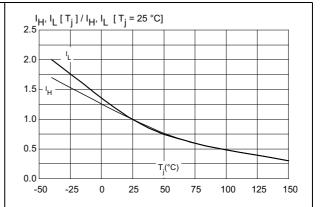
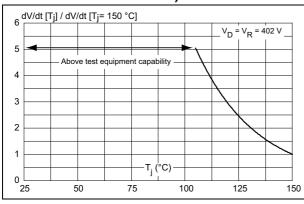


Figure 7. Relative variation of static dV/dt immunity versus junction temperature (typical values)

Figure 8. Surge peak on-state current versus number of cycles



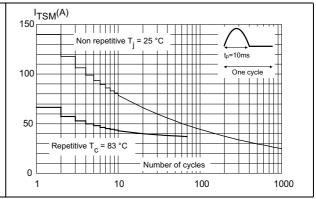


Figure 9. Non-repetitive surge peak on-state current for a sinusoidal pulse (tp < 10 ms)

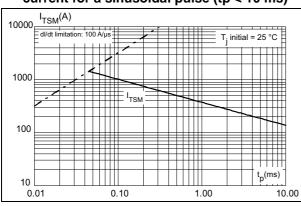
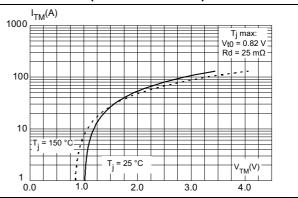
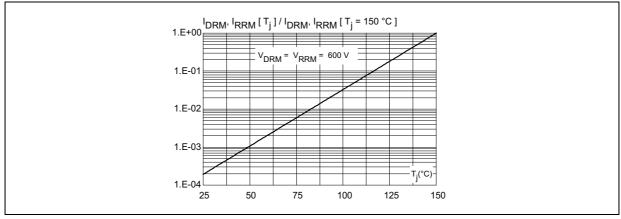


Figure 10. On-state characteristics (maximum values)



TN1610H-6FP Characteristics

Figure 11. Relative variation of leakage current versus junction temperature (tp < 10 ms)



Package information TN1610H-6FP

## 2 Package information

- Epoxy meets UL94, V0
- Lead-free package
- Halogen free molding compound
- Recommended torque: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

Figure 12. TO-220FPAB outline Н Dia L6 L2 L7 L3 L5 D F1 L4 F2 F Ε G1 G

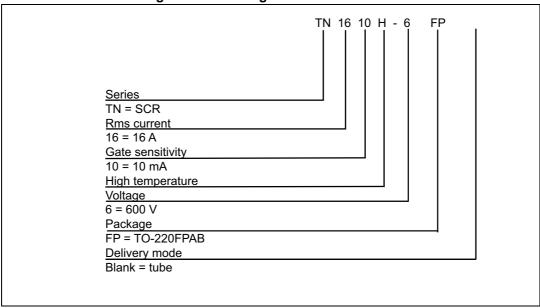
Table 6. TO-220FPAB dimensions

	Dimensions					
Ref.	Millimeters		Inches			
	Min.	Max.	Min.	Max.		
А	4.4	4.6	0.173	0.181		
В	2.5	2.7	0.098	0.106		
D	2.5	2.75	0.098	0.108		
Е	0.45	0.70	0.018	0.027		
F	0.75	1	0.030	0.039		
F1	1.15	1.70	0.045	0.067		
F2	1.15	1.70	0.045	0.067		
G	4.95	5.20	0.195	0.205		
G1	2.4	2.7	0.094	0.106		
Н	10	10.4	0.393	0.409		
L2	16 <sup>-</sup>	Гур.	0.63	Тур.		
L3	28.6	30.6	1.126	1.205		
L4	9.8	10.6	0.386	0.417		
L5	2.9	3.6	0.114	0.142		
L6	15.9	16.4	0.626	0.646		
L7	9.00	9.30	0.354	0.366		
Dia.	3.00	3.20	0.118	0.126		

Ordering information TN1610H-6FP

# 3 Ordering information

Figure 13. Ordering information scheme



**Table 7. Ordering information** 

Order code	Marking	Package	Weight	Base qty	Delivery mode	
TN1610H-6FP	TN1610H6	TO-220FPAB	2.0 g	50	Tube	

## 4 Revision history

Table 8. Document revision history

Date	Revision	Changes
25-Feb-2015	1	Initial release.

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